

## MOSFETs

Order code	Manufacturer code	Description
47-0160	n/a	ZVN3306A N CHANNEL MOSFET (RC)

MOSFETs	Page 1 of 4
The enclosed information is believed to be correct, Information may change without notice due to product improvement. Users should ensure that the product is suitable for their use. E. & O. E.	Revision A 20/02/2007

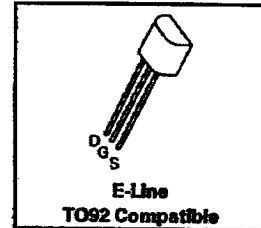
**N-CHANNEL ENHANCEMENT  
MODE VERTICAL DMOS FET**

**ZVN3306A**

ISSUE 2 - MARCH 94

**FEATURES**

- \* 60 Volt  $V_{DS}$
- \*  $R_{DS(on)}=5\Omega$



**ABSOLUTE MAXIMUM RATINGS.**

PARAMETER	SYMBOL	VALUE	UNIT
Drain-Source Voltage	$V_{DS}$	60	V
Continuous Drain Current at $T_{amb}=25^{\circ}C$	$I_D$	270	mA
Pulsed Drain Current	$I_{DM}$	3	A
Gate-Source Voltage	$V_{GS}$	$\pm 20$	V
Power Dissipation at $T_{amb}=25^{\circ}C$	$P_{tot}$	625	mW
Operating and Storage Temperature Range	$T_j, T_{stg}$	-55 to +150	$^{\circ}C$

**ELECTRICAL CHARACTERISTICS (at  $T_{amb} = 25^{\circ}C$  unless otherwise stated).**

PARAMETER	SYMBOL	MIN.	MAX.	UNIT	CONDITIONS.
Drain-Source Breakdown Voltage	$BV_{DSS}$	60		V	$I_D=1mA, V_{GS}=0V$
Gate-Source Threshold Voltage	$V_{GS(th)}$	0.8	2.4	V	$I_D=1mA, V_{DS}=V_{GS}$
Gate-Body Leakage	$I_{GSS}$		20	nA	$V_{GS}=\pm 20V, V_{DS}=0V$
Zero Gate Voltage Drain Current	$I_{DSS}$		0.5 50	$\mu A$ $\mu A$	$V_{DS}=60V, V_{GS}=0$ $V_{DS}=48V, V_{GS}=0V, T=125^{\circ}C(2)$
On-State Drain Current(1)	$I_{D(on)}$	750		mA	$V_{DS}=18V, V_{GS}=10V$
Static Drain-Source On-State Resistance (1)	$R_{DS(on)}$		5	$\Omega$	$V_{GS}=10V, I_D=500mA$
Forward Transconductance(1)(2)	$g_{fs}$	150		mS	$V_{DS}=18V, I_D=500mA$
Input Capacitance (2)	$C_{iss}$		35	pF	$V_{DS}=18V, V_{GS}=0V, f=1MHz$
Common Source Output Capacitance (2)	$C_{oss}$		25	pF	
Reverse Transfer Capacitance (2)	$C_{rss}$		8	pF	
Turn-On Delay Time (2)(3)	$t_{d(on)}$		5	ns	$V_{DD}=18V, I_D=500mA$
Rise Time (2)(3)	$t_r$		7	ns	
Turn-Off Delay Time (2)(3)	$t_{d(off)}$		6	ns	
Fall Time (2)(3)	$t_f$		8	ns	

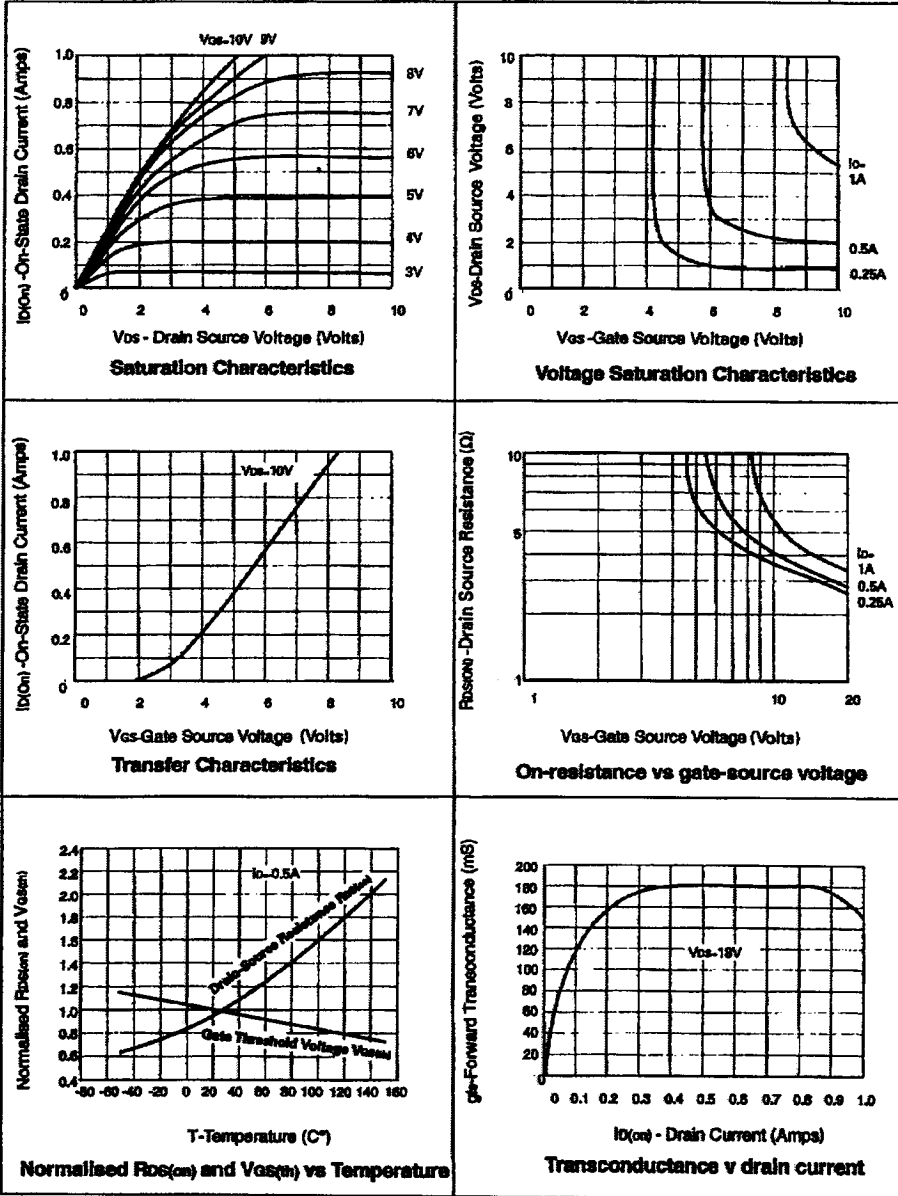
(1) Measured under pulsed conditions. Width=300 $\mu s$ . Duty cycle  $\leq 2\%$

(2) Sample test.

(3) Switching times measured with 50 $\Omega$  source impedance and <5ns rise time on a pulse generator

# ZVN3306A

## TYPICAL CHARACTERISTICS



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